

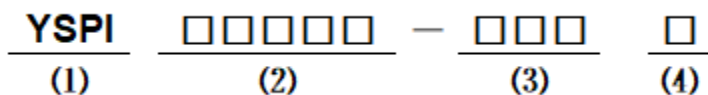
■ Features

- Molding Inductor, low noise.
- Low Profile, Low Temp.
- Large Current (Over 15A).
- Customize For Different Need.
- Operating temperature: $-55^{\circ}\text{C} \sim +125^{\circ}\text{C}$ (Including self-temperature rise).

■ Applications

- General Electronic.
- Video Device, TV, TFT.
- Power Module for PC.
- NB/Lap Top Computer.
- Server, VGA Card/Module.
- DC/DC converter.

■ Product Identification



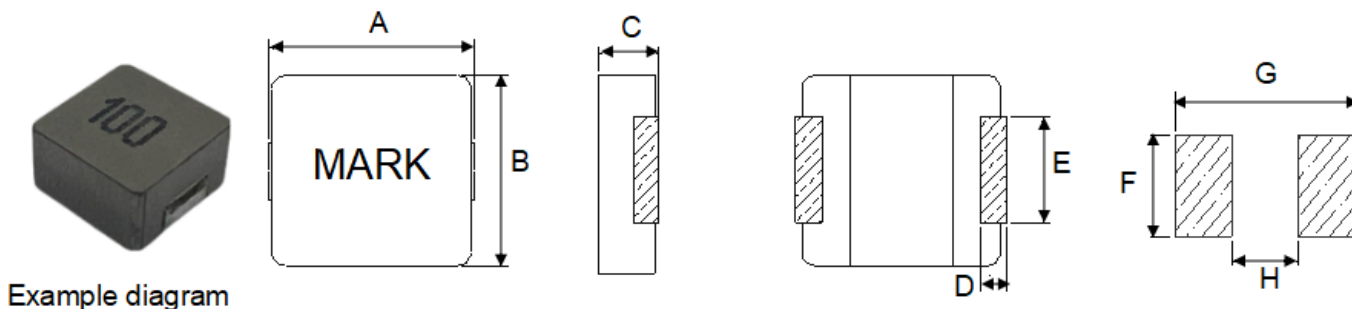
(1) : Type

(2) : Dimensions

(3) : Inductance value

(4) : Inductance Tolerance: N=±30%, M=±20%

■ Shapes and Dimensions (Unit: mm)



TYPE	A Max.	B	C	D	E	F Typ.	G Typ.	H Typ.
YSPI1040S	11.5	10.0±0.3	3.8±0.2	2.0±0.5	3.0±0.5	4.1	13.6	5.4

■ YSPI1040S Series

Part Number	Inductance (μ H) @100KHz/1V	DCR Max. (m Ω)	Saturation Current Isat(A) Typ.	Heat Rating Current Irms(A) Typ.
YSPI1040S-R15M	0.15 $\pm$ 20%	0.65	75.0	45.0
YSPI1040S-R22M	0.22 $\pm$ 20%	1.0	60.0	35.0
YSPI1040S-R22MD	0.22 $\pm$ 20%	0.6 $\pm$ 7%	72.0	50.0
YSPI1040S-R30M	0.30 $\pm$ 20%	1.1	45.0	35.0
YSPI1040S-R36M	0.36 $\pm$ 20%	1.2	45.0	30.0
YSPI1040S-R36MD	0.36 $\pm$ 20%	0.76 $\pm$ 7%	50.0	40.0
YSPI1040S-R47M	0.47 $\pm$ 20%	1.7	40.0	30.0
YSPI1040S-R56M	0.56 $\pm$ 20%	1.8	33.0	25.0
YSPI1040S-R68M	0.68 $\pm$ 20%	2.4	30.0	23.0
YSPI1040S-R68MD	0.68 $\pm$ 20%	1.6 $\pm$ 7%	34.0	28.0
YSPI1040S-R80M	0.80 $\pm$ 20%	2.7	29.0	23.0
YSPI1040S-1R0M	1.0 $\pm$ 20%	3.3	28.0	19.0
YSPI1040S-1R0MD	1.0 $\pm$ 20%	2.3 $\pm$ 7%	29.0	24.0
YSPI1040S-1R5M	1.5 $\pm$ 20%	4.2	24.0	16.0
YSPI1040S-2R2M	2.2 $\pm$ 20%	7.0	16.5	12.0
YSPI1040S-3R3M	3.3 $\pm$ 20%	11.8	16.0	11.0
YSPI1040S-4R7M	4.7 $\pm$ 20%	20.0	13.0	9.0
YSPI1040S-6R8M	6.8 $\pm$ 20%	25.0	12.0	8.5
YSPI1040S-8R2M	8.2 $\pm$ 20%	27.0	9.0	8.0
YSPI1040S-100M	10 $\pm$ 20%	30.0	8.5	7.8
YSPI1040S-150M	15 $\pm$ 20%	45.0	7.0	6.5
YSPI1040S-220M	22 $\pm$ 20%	66.0	5.5	5.0
YSPI1040S-330M	33 $\pm$ 20%	92.0	4.8	4.4
YSPI1040S-470M	47 $\pm$ 20%	145	3.5	3.3
YSPI1040S-680M	68 $\pm$ 20%	195	3.0	2.5
YSPI1040S-820M	82 $\pm$ 20%	285	2.8	2.3
YSPI1040S-101M	100 $\pm$ 20%	340	2.3	2.0

※ All test data is referenced to 25 °C ambient

※ Irms (A):DC current (A) that will cause an approximate ΔT of 40 °C(reference ambient temperature is 25 °C)

※ Isat(A):DC current (A) that will cause L0 to drop approximately 30 %.(Internal control standards at 40% MAX)

※ The part temperature (ambient + temp rise) should not exceed 125 °C under worst case operating conditions.
Circuit design, component placement, PWB trace size and thickness, airflow and other cooling provisions all affect the part temperature. Part temperature should be verified in the end application.

■ Mechanical Reliability

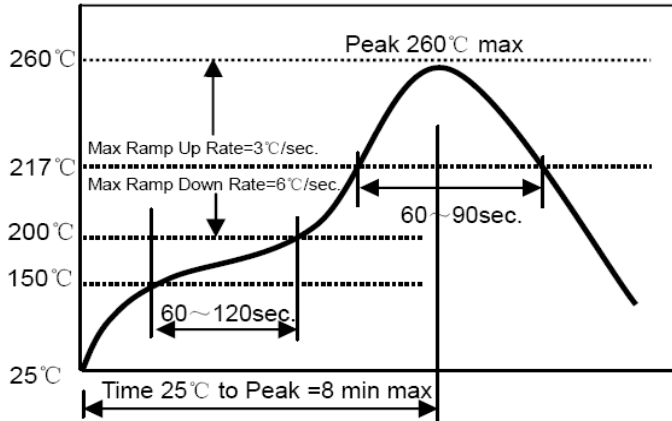
Item	Specification and Requirement	Test Method
Solderability	1. No case deformation or change in visual 2. New solder coverage More than 95%	1.Preheat: 155℃±5℃ , 60S±2S 2.Tin: lead-free. 3.Temperature:240℃±5℃, flux 3.0S±0.5S.
Mechanical shock	1. No case deformation or change in visual 2. $\Delta L/L_0 \leq \pm 10\%$	1. Acceleration: 100G 2. Pulse time: 6ms 3. 3 times in each positive and negative direction of 3 mutual perpendicular directions
Mechanical vibration	1. No case deformation or change in visual 2. $\Delta L/L_0 \leq \pm 10\%$	1. Reflow: 2times 2. Frequency: 10HZ ~ 55HZ ~ 10HZ, 20 Min/Cycles 3. Amplitude: 1.52 mm±10% 4. Directions: X,Y,Z 5. Time: 12 cycle / direction

■ Endurance Reliability

Item	Specification and Requirement	Test Method
Thermal Shock	Inductance change: Within $\pm 10\%$ Without distinct damage in visual	1. First -55℃ for 30 minutes, last 125℃ for 30 minutes as 1 cycle. Go through 1000 cycles. 2. Max transfer time is 3 minutes. 3. Measured at room temperature after placing for 24±2 hours
Biased Humidity	Inductance change: Within $\pm 10\%$ Without distinct damage in visual	1.Reflow 2 times, 2.85℃,85%RH,1000 hours 3.Measured at room temperature after placing for 24±2 hours
Low temperature storage	Inductance change: Within $\pm 10\%$ Without distinct damage in visual	1. Temperature: -55 $\pm 2^\circ\text{C}$ 2. Time: 1000 hours 3. Measured at room temperature after placing for 24±2 hours
High temperature storage	Inductance change: Within $\pm 10\%$ Without distinct damage in visual	1. Temperature: +125 $\pm 2^\circ\text{C}$ 2. Time: 1000 hours 3. Measured at room temperature after placing for 24±2 hours

■ Recommended Soldering Technologies

Re-flowing Profile



Preheat condition: 150 ~200°C/60~120sec.

Allowed time above 217°C: 60~90sec.

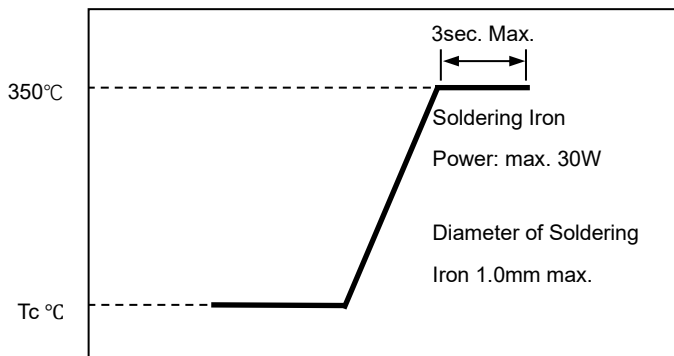
Peak temp: 260°C

Max time at Peak temp: 10 sec.

Solder paste: Sn/3.0Ag/0.5Cu

Allowed Reflow time: 2x max

Iron Soldering Profile



Iron soldering power: Max. 30W

Pre-heating: 150°C/60sec.

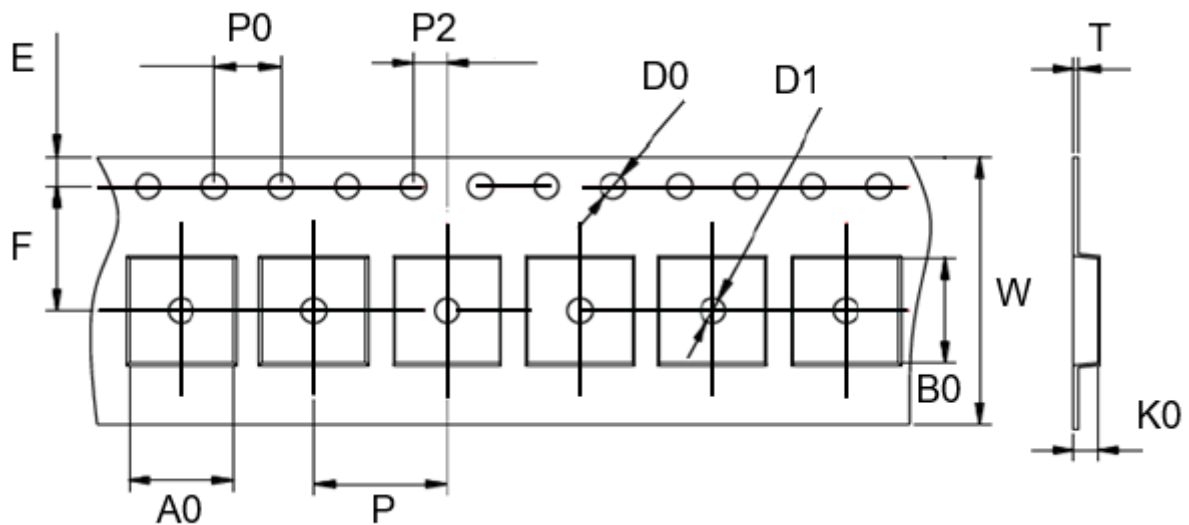
Soldering Tip temperature: 350°C Max.

Soldering time: 3sec. Max.

Solder paste: Sn/3.0Ag/0.5Cu

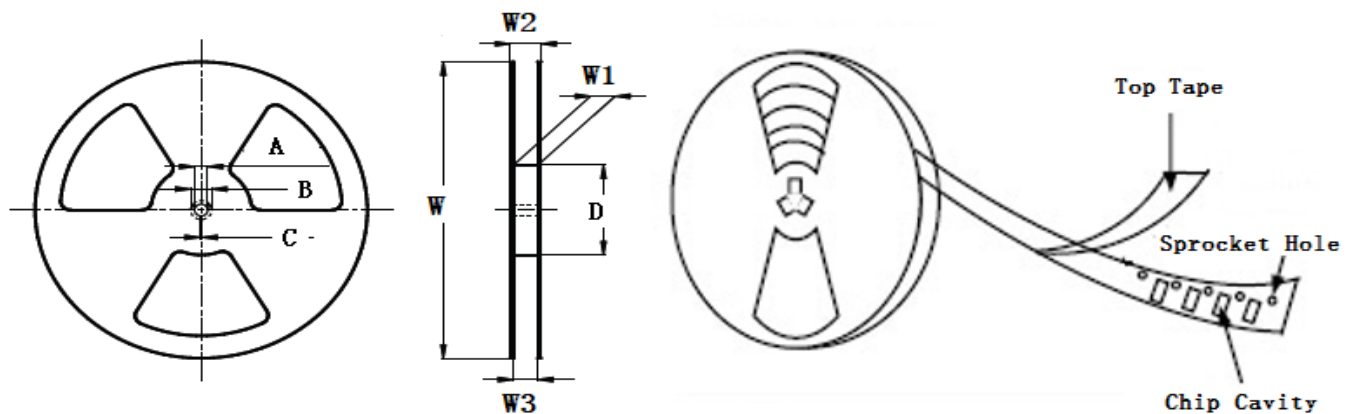
Max.1 times for iron soldering

■ Taping Dimensions(Unit:mm)



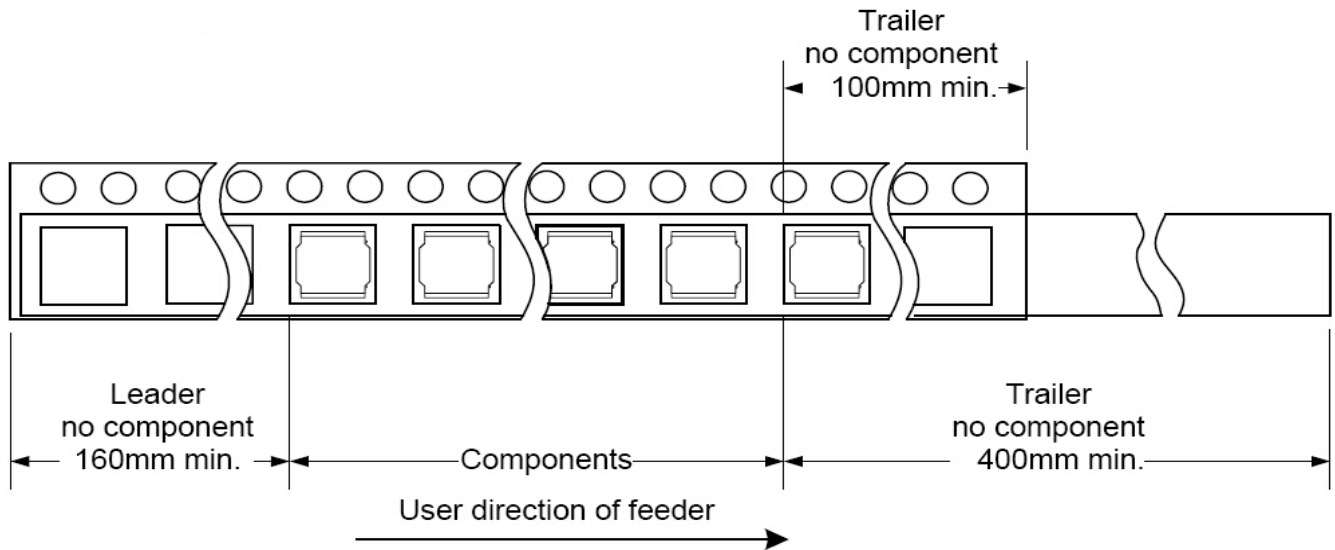
TYPE	W	P	P0	P2	D0	D1	T	A0	B0	K0	E	F	MPQ
YSPI1040S	24.0 ±0.3	16.0 ±0.1	4.0 ±0.1	2.0 ±0.1	1.5 ±0.1	1.5 ±0.1	0.35 ±0.05	10.4 ±0.1	11.6 ±0.1	4.3 ±0.1	1.75 ±0.1	11.5 ±0.1	500

■ Reel Dimensions(Unit:mm)

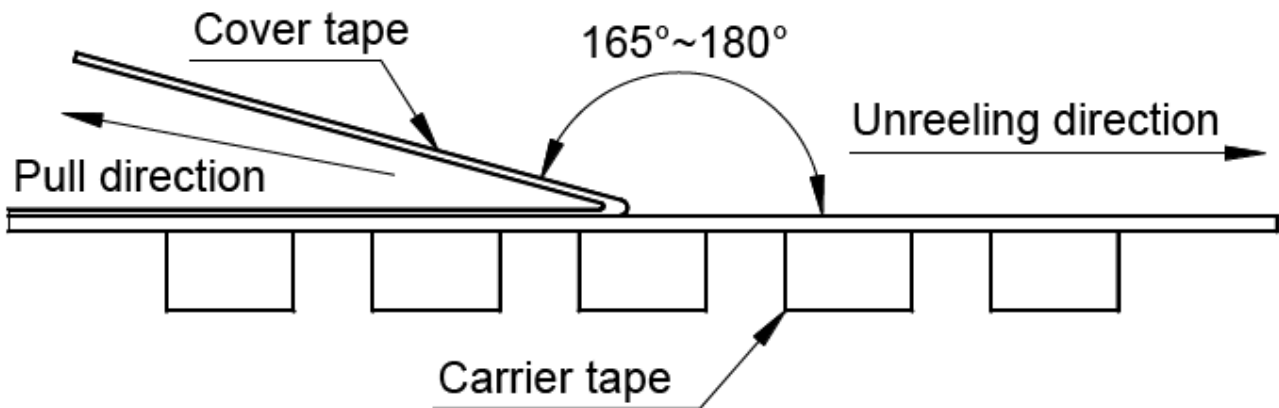


TYPE	W	W1	W2	W3	A	B	C	D
YSPI1040S	330±2.0	24.4±1.5	30.4MAX	23.9 Min	13.0±0.5	21.0±0.8	2.0±0.5	97.0±0.5

■ Direction of rolling



■ Cover tape peel off condition



Cover tape peel force shall be 0.1N to 1.3N.

Reference peel speed 300 ± 10 mm/min.